

EVVOSEMI[®]

THINK CHANGE DO



ESD



TVS



MOS



LDO



Diode



Sensor



DC-DC

Product Specification

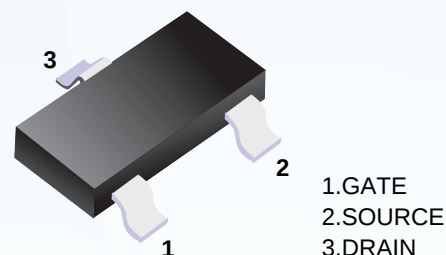
▶ Domestic	Part Number	2N7002K
▶ Overseas	Part Number	2N7002K
▶ Equivalent	Part Number	2N7002K

EV is the abbreviation of name EVVO

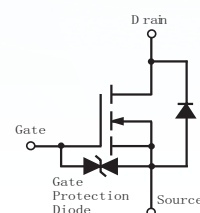
■ N-Channel Enhancement MOSFET

■ Features

- Low On-Resistance: $R_{DS(ON)}$
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected 2KV HBM



■ Simplified outline(SOT-23)



■ Absolute Maximum Ratings $T_a=25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage -Continuous	V_{GS}	± 20	
Drain Current -Continuous (Note:1) -Pulsed	I_D	300	mA
		800	
Power Dissipation (Note 1)	P_D	350	mW
Thermal Resistance.Junction- to-Ambient	R_{thJA}	357	$^\circ\text{C/W}$
Junction Temperature	T_J	150	$^\circ\text{C}$
Junction and Storage Temperature Range	T_{stg}	-55 to 150	

Notes: 1. Device mounted on FR-4 PCB.

■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage (Note.2)	V_{DSS}	$I_D=100\mu\text{A}$, $V_{GS}=0\text{V}$	60			V
Zero Gate Voltage Drain Current (Note.2)	I_{DSS}	$V_{DS}=60\text{V}$, $V_{GS}=0\text{V}$			1	μA
Gate-Body Leakage Current (Note.2)	I_{GSS}	$V_{DS}=0\text{V}$, $V_{GS}=\pm 20\text{V}$			± 10	μA
Gate Threshold Voltage (Note.2)	$V_{GS(th)}$	$V_{DS} = 10\text{V}$, $I_D = 1\text{mA}$	1	1.6	2.5	V
Static Drain-Source On-Resistance (Note.2)	$R_{DS(on)}$	$V_{GS}=10\text{V}$, $I_D=500\text{mA}$			2	Ω
		$V_{GS}=10\text{V}$, $I_D=50\text{mA}$			3	
Forward Transfer Admittance (Note.2)	$ Y_{fs} $	$V_{GS}=10\text{V}$, $I_D=200\text{mA}$	80			ms
Input Capacitance	C_{iss}	$V_{GS}=0\text{V}$, $V_{DS}=25\text{V}$, $f=1\text{MHz}$			50	pF
Output Capacitance	C_{oss}				25	
Reverse Transfer Capacitance	C_{rss}				5	
Total Gate Charge	Q_g	$V_{GS}=4.5\text{V}$, $V_{DS}=15\text{V}$, $I_D=200\text{mA}$			0.8	nC
Turn-On DelayTime	$t_{d(on)}$	$I_D=200\text{mA}$, $V_{DS}=30\text{V}$, $R_G=10\Omega$, $V_{GEN}=10\text{V}$, $R_L=150\Omega$			20	ns
Turn-Off DelayTime	$t_{d(off)}$				40	

Note: 2. Short duration test pulse used to minimize self-heating effect.

■ Typical Characteristics

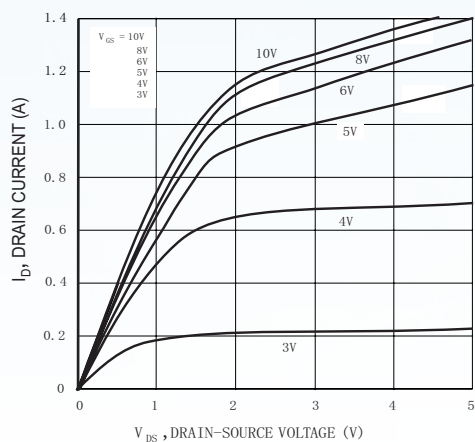


Fig. 1 Typical Output Characteristics

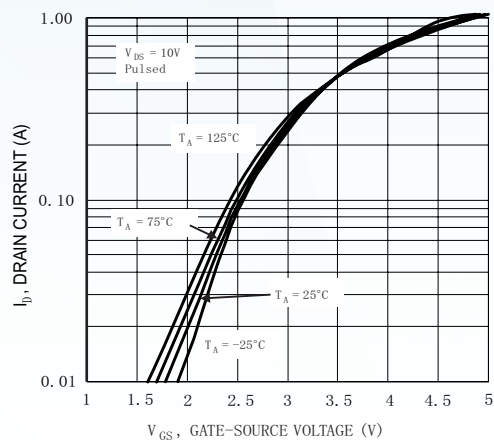


Fig. 2 Typical Transfer Characteristics

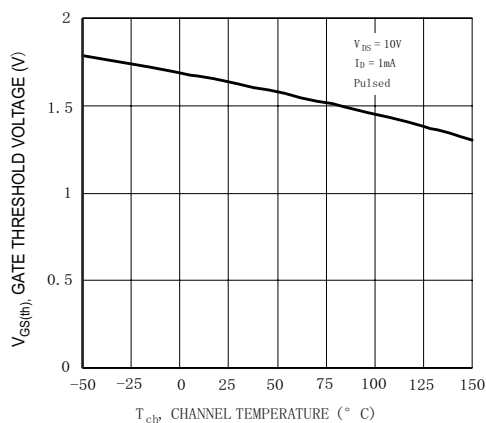


Fig. 3 Gate Threshold Voltage vs. Channel Temperature

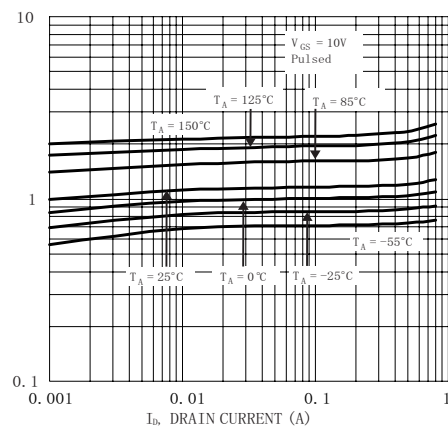


Fig. 4 Static Drain-Source On-Resistance vs. Drain Current

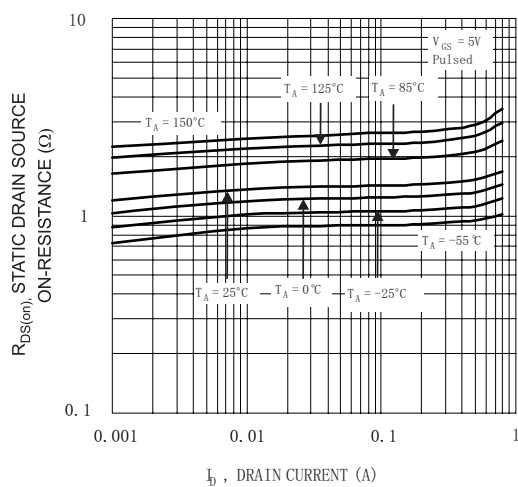


Fig. 5 Static Drain-Source On-Resistance vs. Drain Current

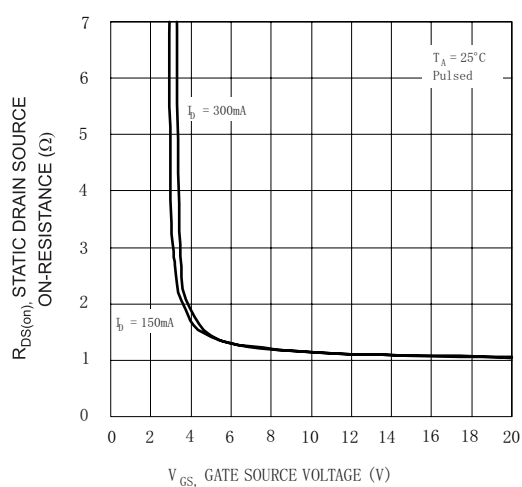


Fig. 6 Static Drain-Source On-Resistance vs. Gate-Source Voltage

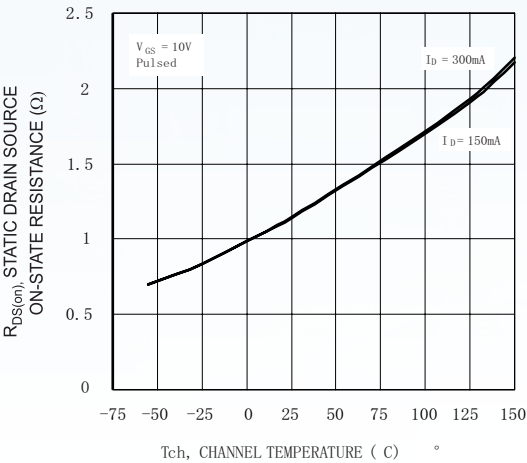


Fig. 7 Static Drain-Source On-State Resistance vs. Channel Temperature

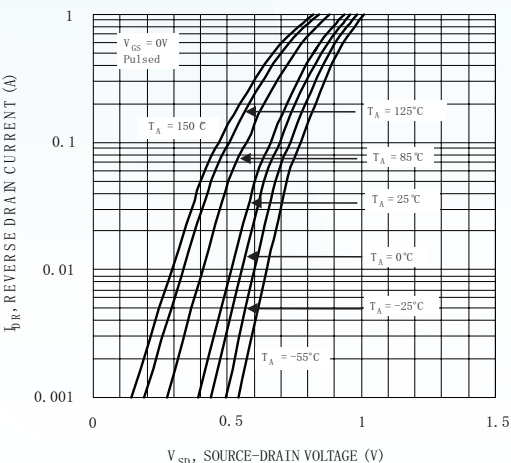


Fig. 8 Reverse Drain Current vs. Source-Drain Voltage

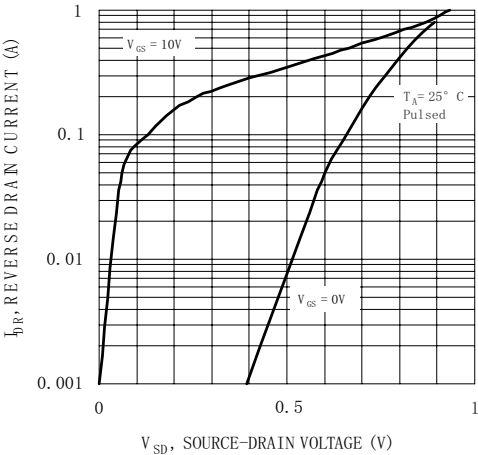


Fig. 9 Reverse Drain Current vs. Source-Drain Voltage

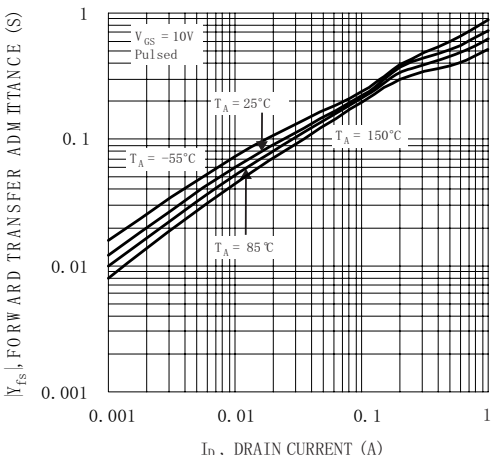
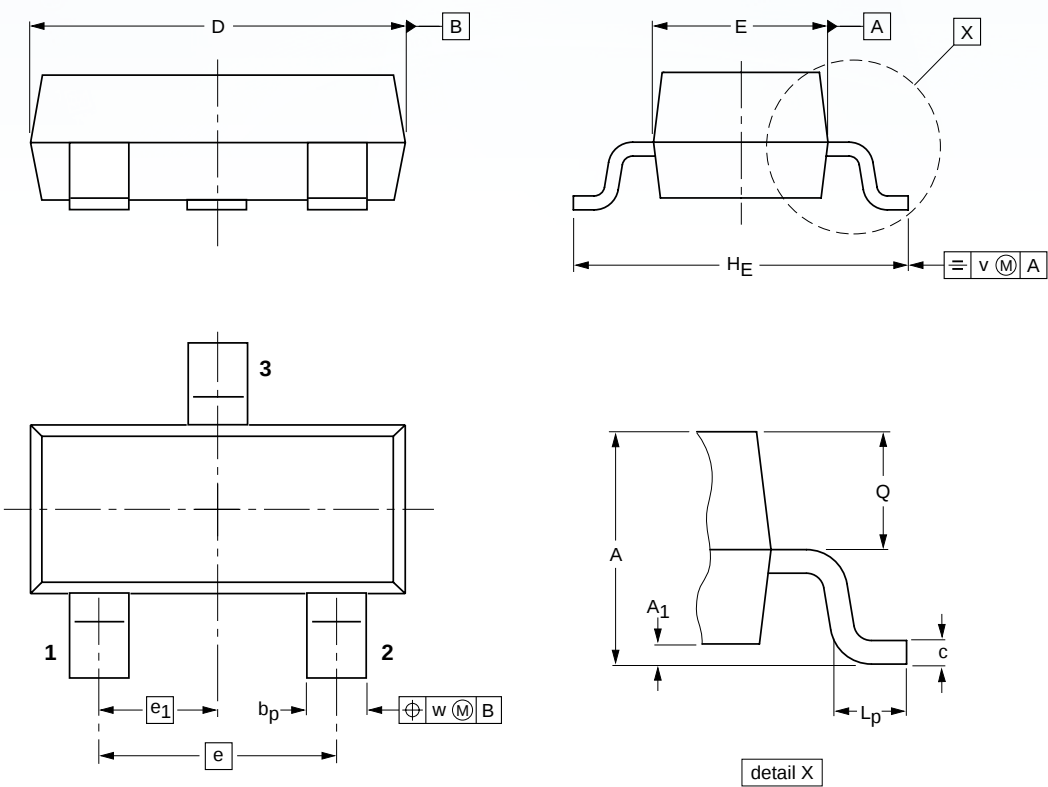


Fig. 10 Forward Transfer Admittance vs. Drain Current

■ SOT-23



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max.	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

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